



## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. .... 10/041,896 -  
 Confirmation No. .... 5572  
 Filing Date ..... January 7, 2002 -  
 Inventor ..... Brenda D. Kraus et al.  
 Assignee ..... Micron Technology, Inc.  
 Group Art Unit ..... 2813  
 Examiner ..... Yennhu B. Huynh  
 Attorney's Docket No. .... MI22-1859  
 Customer No. .... 021567  
 Title: DRAM Circuitry Having Storage Capacitors Which Include Capacitor  
 Dielectric Regions Comprising Aluminum Nitride

RESPONSE TO SEPTEMBER 9, 2003 FINAL OFFICE ACTION  
PRELIMINARY AMENDMENT TO ACCOMPANY RCE FILING

To: Mail Stop RCE  
 Commissioner for Patents  
 P. O. Box 1450  
 Alexandria, VA 22313-1450

VIA EXPRESS MAIL

From: Mark S. Matkin (Tel. 509-624-4276; Fax 509-838-3424)  
 Wells St. John P.S.  
 601 West First Avenue, Suite 1300  
 Spokane, WA 99201-3828

Responsive to the Final Office Action dated September 9, 2003, Applicant  
 amends and remarks as follows:

AMENDMENTS

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 TECHNOLOGY CENTER 2800